



\* http://stc-mditr.org/research/lsoe/highlights/highlight4.cfm

- I. Introduction to Nanoelectronics (01) 01 Micro- or nano-electronics ?
- II. Electromagnetism (02 & 03)
  - 02 Maxwell equations

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# 09 Nanomeasurements

- Scanning tunnelling microscope
- Scanning tunnelling spectroscopy
  - Atom manipulation
  - Atomic force microscope
- Transmission electron microscope
  - Scanning electron microscope
    - Surface analysis



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In 1982, Gerd Binnig and Heinrich Rohrer invented scanning tunnelling microscopy :



\* http://www.wikipedia.org/ \*\* http://nobelprize.org/

#### Si Surface Reconstruction

Atomic resolution by STM was clearly proved by Si surface observation in 1983 :





#### Si (111) $7 \times 7$ Surface Reconstruction



\* http://www.ss.teen.setsunan.ac.jp/2006/si-7x7-das-vr.html



An individual atom can be manipulated by a STM tip shown by Donald Eigler in 1989 :

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 $\rightarrow$ 



# Atomic Force Microscope (AFM)

In 1985, Gerd Binnig invented atomic force microscopy :



\* http://www.wikipedia.org/





 $\rightarrow$  Similarly, scanning SQUID  $^{\scriptscriptstyle +}$  / Hall  $^{\scriptscriptstyle \pm}$  microscope were developed.

<sup>†</sup>C. C. Tsuei *et al.*, *Phys. Rev. Lett.* **73**, 593 (1994). <sup>‡</sup>A. Oral *et al.*, *Appl. Phys. Lett.* **69**, 1324 (1996).

> \* Y. Martin, H. K. Wickramasinghe, *Appl. Phys. Lett.* **50**, 1455 (1987). \*\* http://www.veeco.com/



\* A. Hirohata, M. Samiepour, M. Corbetta, "Magnetic Force Microscopy for Magnetic Recording and Devices," in "Electrical Atomic Force Microscopy for Nanoelectronics" Umberto Celano (Ed.) (Springer, Berlin, Germany, 2019) p. 231-265.



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20 nm thick Fe dots (1  $\mu m$  diameter)



30 nm thick NiFe dots (5  $\mu m)$ 

# Transmission Electron Microscope (TEM)

In 1933, Ernst A. F. Ruska and Max Knoll built an electron microscope :

- Preliminary electron microscope (×  $\$  ) in 1931
- Improved to  $\times$  in 1933
- Commercially available from Siemens in 1938







- Sample thickness : 200 ~ 300 nm
- Magnetic field acts as a lens to electron-beam : Hans W. H. Busch in 1927

Transmission Electron Microscope

#### Early TEM Images

Early oxide replica of etched AI :

Si-Fe :



FIG. 1 TEM image of an early oxide replica of etched aluminum (Mahl 1941); horizontal field width = 9 µm.



FIG. 3 Electron-beam scanner image of silicon iron showing electron channeling contrast; horizontal field width = 50 mm. (Knoll 1935).

\* http://www-g.eng.cam.ac.uk/125/achievements/mcmullan/mcm.htm

# Scanning Electron Microscope (SEM)

In 1937, Manfred von Ardenne developed a scanning electron microscope :



\*\* http://bluedianni.blogspot.com/2008/05/scanning-electron-microscopy-sem.html

SEM image of etched brass :

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X



FIG. 8 Micrograph of etched brass produced by the SEM of Zworykin et al. (1942a); horizostal field width = 18 µm.



FIG. 12 Photograph of SEM 1 taken in 1953.



Fig. 13 The first magnetically focussed scanning electron microscope (SEM 3) built by K.C.A. Smith for the Pulp and Paper Research Institute of Canada (Smith 1959, 1961).

\* http://www-g.eng.cam.ac.uk/125/achievements/mcmullan/mcm.htm

## Scanning Transmission Electron Microscope (STEM)

By scanning electron-beam, TEM resolution can be improved significantly :



• 0.8 Å resolution





#### By STEM, H atoms were directly observed :





\* S. D. Findlay et al., Appl. Phys. Exp. 3, 116603 (2010).



Auger electrons are found by Lise Meitner in 1922 and Pierre V. Auger in 192





\* http://www.phi.com/ \*\* http://www.jeol.com/





Example of  $Co_2TiSn$  :



## Surface Structural Analysis

Reflection high energy electron diffraction (RHEED) :





RHEED patterns of Co<sub>2</sub>FeAl grown on GaAs (001) :



Co<sub>2</sub>FeAl (001) <110> || GaAs (001) <110>



### Surface Analysis

#### Major techniques for surface analysis :

Techniques	Incident beam	Signals	Composition	Structure	Electronic state
Auger electron spectroscopy (AES)	DCum		Qualitative analysis		Auger electron spectra
Auger electron diffraction (AED)	Electron- beam	Auger electrons		Auger diffraction (~ a few atoms)	
Electron probe micro- analyzer (EPMA)	 		Qualitative analysis (sensitivity ~ 0.1 %)		X-ray spectra
Energy dispersive X-ray analysis (EDX)	Electron- beam	Characteristic X-ray	Qualitative analysis		X-ray spectra
X-ray photoelectron spectroscopy (XPS)	Electron- beam	Photo-emission electrons	Qualitative analysis		Atomic binding energy
Photoemission electron microscopy (PEEM)	X-ray / photon	Photo-emission electrons	Atom mapping		Atomic binding energy
Secondary ion mass spectroscopy (SIMS)	Electron- beam	Secondary electrons	Qualitative analysis		
Electron energy-loss spectroscopy (EELS)	Electron- beam	Secondary electrons	Surface absorption spectra		
Reflection high energy diffraction (RHEED)	El chara			Reflected diffraction patterns	
Low energy electron diffraction (LEED)	Electron- beam	Reflected electron-beam		Back-scattered diffraction patterns	
X-ray absorption fine structure (XAFS)	X-ray	Photo-emission electrons	Surface absorption spectra		
X-ray diffraction (XRD)	X-ray	Reflected X-ray		X-ray diffraction	
Transmission electron diffraction (TED)	Electron- beam	Transmission electrons		Diffraction patterns (t < 30 nm)	

\* D. P. Woodruff and T. A. Delchar, Modern Techniques of Surface Science (Cambridge University Press, Cambridge, 1994).



Analytical Resolution versus Detection Limit

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\* http://www.nanoscience.co.jp/surface\_analysis/technique/RBS-HFS-PIXE-NRA.html